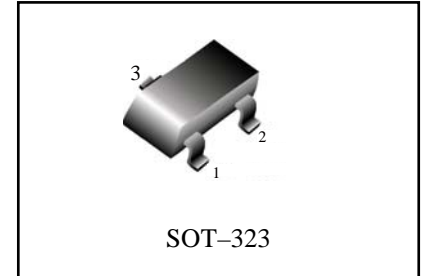


# General Purpose Transistors

## PNP Silicon

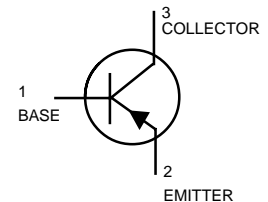
### FEATURE

- Collector current capability  $I_C = -500$  mA.
- Collector-emitter voltage  $V_{CEO(max)} = -45$  V.
- General purpose switching and amplification.
- NPN complement: BC817U Series.
- We declare that the material of product compliance with RoHS requirements.



### DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
BC807U-A	5A1	3000/Tape&Reel
BC807U-B	5B1	3000/Tape&Reel
BC807U-C	5C1	3000/Tape&Reel



### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	$V_{CEO}$	-45	V
Collector–Base Voltage	$V_{CBO}$	-50	V
Emitter–Base Voltage	$V_{EBO}$	-5.0	V
Collector Current — Continuous	$I_C$	-500	mA <sub>dc</sub>

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (1) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

1. FR-5 = 1.0 x 0.75 x 0.062 in.
2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



# BC807U

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ( $I_C = -10\text{ mA}$ )	$V_{(BR)CEO}$	-45	—	—	V
Collector–Emitter Breakdown Voltage ( $V_{EB} = 0, I_C = -10\ \mu\text{A}$ )	$V_{(BR)CES}$	-50	—	—	V
Emitter–Base Breakdown Voltage ( $I_E = -1.0\ \mu\text{A}$ )	$V_{(BR)EBO}$	-5.0	—	—	V
Collector Cutoff Current ( $V_{CB} = -20\text{ V}$ ) ( $V_{CB} = -20\text{ V}, T_J = 150^\circ\text{C}$ )	$I_{CBO}$	— —	— —	-100 -5.0	nA $\mu\text{A}$

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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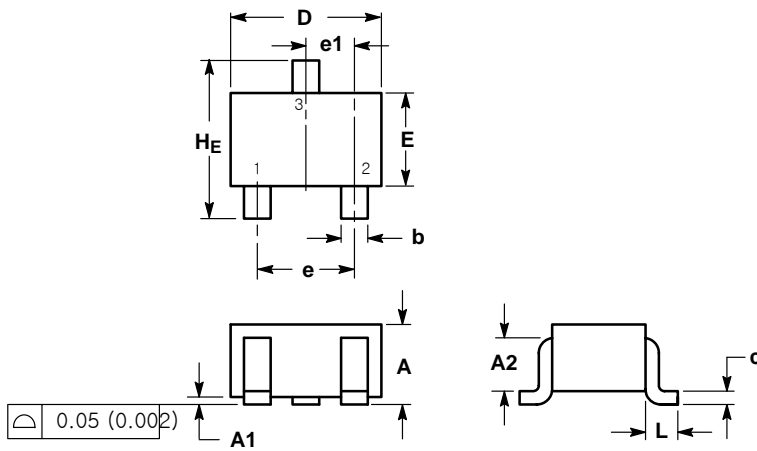
### ON CHARACTERISTICS

DC Current Gain ( $I_C = -100\text{ mA}, V_{CE} = -1.0\text{ V}$ )  ( $I_C = -500\text{ mA}, V_{CE} = -1.0\text{ V}$ )	$h_{FE}$ BC807U-A BC807U-B BC807U-C	100 160 250 40	— — — —	250 400 600 —	—
Collector–Emitter Saturation Voltage ( $I_C = -500\text{ mA}, I_B = -50\text{ mA}$ )	$V_{CE(sat)}$	—	—	-0.7	V
Base–Emitter On Voltage ( $I_C = -500\text{ mA}, V_{CE} = -1.0\text{ V}$ )	$V_{BE(on)}$	—	—	-1.2	V

### SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ( $I_C = -10\text{ mA}, V_{CE} = -5.0\text{ V}_{dc}, f = 100\text{ MHz}$ )	$f_T$	100	—	—	MHz
Output Capacitance ( $V_{CB} = -10\text{ V}, f = 1.0\text{ MHz}$ )	$C_{obo}$	—	10	—	pF

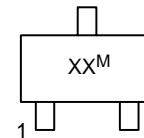
## SC-70 (SOT-323)



NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.7 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.425 REF			0.017 REF		
He	2.00	2.10	2.40	0.079	0.083	0.095

### GENERIC MARKING DIAGRAM



- XX = Specific Device Code
- M = Date Code
- = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

